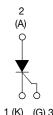


### VS-40TPS16PbF, VS-40TPS16-M3

Vishay Semiconductors

## **High Voltage Phase Control Thyristor, 40 A**



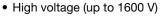


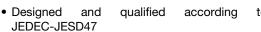
TO-247AC

O	0
1 (K)	(G) 3

PRODUCT SUMMARY					
Package	TO-247AC				
Diode variation	Single SCR				
I <sub>T(AV)</sub>	35 A				
$V_{DRM}/V_{RRM}$	1600 V				
$V_{TM}$	1.45 V				
I <sub>GT</sub>	150 mA				
TJ	- 40 °C to 125 °C				

#### **FEATURES**







• Compliant to RoHS Directive 2002/95/EC

• 125 °C max. operating junction temperature

 Halogen-free according to IEC 61249-2-21 definition (-M3 only)



#### **APPLICATIONS**

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

#### **DESCRIPTION**

The VS-40TPS16... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I <sub>T(AV)</sub>	Sinusoidal waveform	35	A			
I <sub>RMS</sub>		55	^			
V <sub>RRM</sub> /V <sub>DRM</sub>		1600	V			
I <sub>TSM</sub>		500	A			
V <sub>T</sub>	40 A, T <sub>J</sub> = 25 °C	1.45	V			
dV/dt		1000	V/µs			
dl/dt		100	A/µs			
T <sub>J</sub>		- 40 to 125	°C			

VOLTAGE RATINGS							
PART NUMBER	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA				
VS-40TPS16PbF, VS-40TPS16-M3	1600	1700	10				



# VS-40TPS16PbF, VS-40TPS16-M3

## Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS	3					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current	I <sub>T(AV)</sub>	T <sub>C</sub> = 79 °C, 180° conduction half sine w	ave	35		
Maximum continuous RMS on-state current as AC switch	I <sub>T(RMS)</sub>			55	Α	
Maximum peak, one-cycle	I	10 ms sine pulse, rated V <sub>RRM</sub> applied		500		
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no voltage reapplied		600		
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	Initial $T_J = T_J$ maximum	1250	A <sup>2</sup> s	
Maximum 1-t for fusing	ITL	10 ms sine pulse, no voltage reapplied	. 0	1760		
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10 ms, no voltage reapplied		12 500	A²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>			1.02	V	
High level value of threshold voltage	V <sub>T(TO)2</sub>	T 105 °C		1.23		
Low level value of on-state slope resistance	r <sub>t1</sub>	T <sub>J</sub> = 125 °C		9.74		
High level value of on-state slope resistance	r <sub>t2</sub>			7.50	mΩ	
Maximum peak on-state voltage	$V_{TM}$	110 A, T <sub>J</sub> = 25 °C		1.85	V	
Maximum rate of rise of turned-on current	dI/dt	T <sub>J</sub> = 25 °C		100	A/μs	
Maximum holding current	I <sub>H</sub>			150		
Maximum latching current	ΙL		300	A		
Maximum rayaya and divact lackage aurent	1 /1	T <sub>J</sub> = 25 °C		0.5	mA	
Maximum reverse and direct leakage current	d direct leakage current $I_{RRM}/I_{DRM}$ $T_{J} = 125  ^{\circ}C$ $V_{R} = Rated  V_{RRM}/V_{DRM}$		DRM	10	1	
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to 80 % $V_{DRM}$ ,	R <sub>g</sub> -k = Open	1000	V/µs	

TRIGGERING					
PARAMETER	SYMBOL	TE	EST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P <sub>GM</sub>			10	W
Maximum average gate power	P <sub>G(AV)</sub>			2.5	VV
Maximum peak gate current	I <sub>GM</sub>			2.5	Α
Maximum peak negative gate voltage	- V <sub>GM</sub>			10	
	V <sub>GT</sub>	T <sub>J</sub> = - 40 °C		4.0	V
Maximum required DC gate voltage to trigger		T <sub>J</sub> = 25 °C	Anode supply = 6 V resistive load	2.5	
voltage to trigger		T <sub>J</sub> = 125 °C		1.7	
		T <sub>J</sub> = - 40 °C		270	
Maximum required DC gate current to trigger		T <sub>J</sub> = 25 °C		150	mA
Maximum required DC gate current to trigger	I <sub>GT</sub>	T <sub>J</sub> = 125 °C		80	IIIA
		$T_{J} = 25  ^{\circ}\text{C}, \text{ for } 40^{\circ}$	TPS08A	40	
Maximum DC gate voltage not to trigger	$V_{GD}$	T. = 105 °C V	0.25	V	
Maximum DC gate current not to trigger	I <sub>GD</sub>	T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = Rated value		6	mA



THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		$T_J, T_{Stg}$		- 40 to 125	°C	
Maximum thermal resistance, junction to case		$R_{thJC}$	DC operation	0.6		
Maximum thermal resistance, junction to ambient	·			40	°C/W	
Maximum thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2		
Approximate weight				6	g	
Approximate weight				0.21	OZ.	
Mounting torque	minimum			6 (5)	kgf · cm	
Woulding torque	maximum			12 (10)	(lbf $\cdot$ in)	
Marking device			Case style TO-247AC	40TPS16		

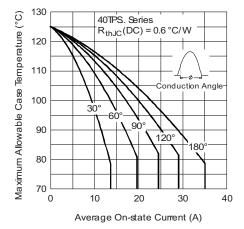


Fig. 1 - Current Rating Characteristics

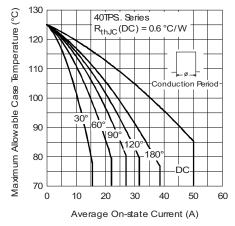


Fig. 2 - Current Rating Characteristics

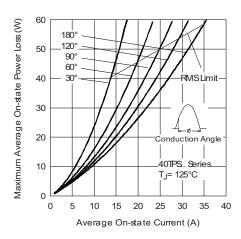


Fig. 3 - On-State Power Loss Characteristics

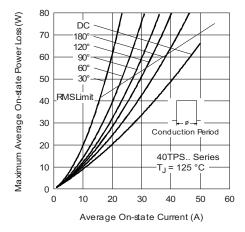


Fig. 4 - On-State Power Loss Characteristics

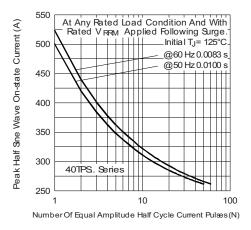


Fig. 5 - Maximum Non-Repetitive Surge Current

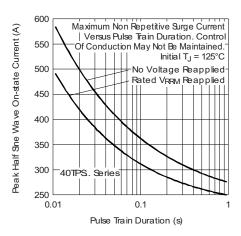


Fig. 6 - Maximum Non-Repetitive Surge Current

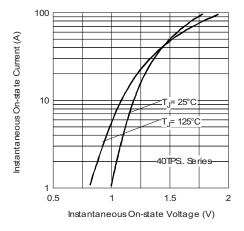


Fig. 7 - On-State Voltage Drop Characteristics

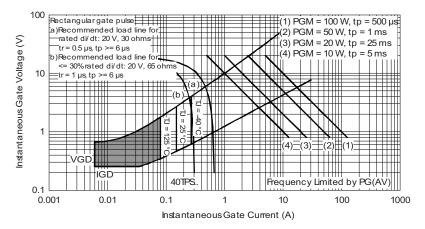


Fig. 8 - Gate Characteristics

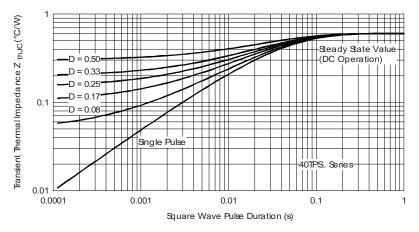
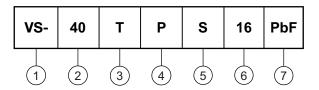


Fig. 9 - Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (40 = 40 A)
- 3 Circuit configuration:

T = Thyristor

4 - Package:

P = TO-247

5 - Type of silicon:

S = Standard recovery rectifier

6 - Voltage rating (16 = 1600 V)

7 - Environmental digit:

PbF = Lead (Pb)-free and RoHS compliant

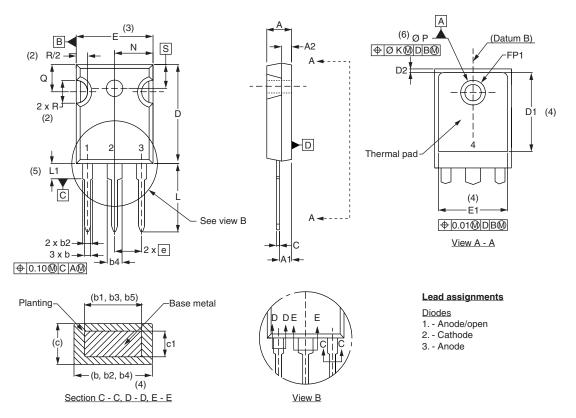
-M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-40TPS16PbF	25	500	Antistatic plastic tubes			
VS-40TPS16-M3	25	500	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95223				
Dort marking information	TO-247AC PbF	www.vishay.com/doc?95226		
Part marking information	TO-247AC -M3	www.vishay.com/doc?95007		



#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.37	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.86	0.015	0.034	
c1	0.38	0.76	0.015	0.030	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	0.51	1.30	0.020	0.051		
E	15.29	15.87	0.602	0.625	3	
E1	13.72	-	0.540	-		
е	5.46	BSC	0.215	BSC		
FK	2.	54	0.0	010		
L	14.20	16.10	0.559	0.634		
L1	3.71	4.29	0.146	0.169		
N	7.62	BSC	0	.3		
ΦР	3.56	3.66	0.14	0.144		
ФР1	1	6.98	-	0.275		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	1.78	0.216		
S	5.51	BSC	0.217	'BSC		

#### **Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c



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Vishay

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